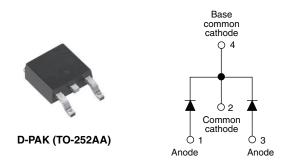
Vishay Semiconductors

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High Performance Schottky Rectifier, 2 x 3.5 A



PRODUCT SUMMARY							
Package	D-PAK (TO-252AA)						
I _{F(AV)}	2 x 3.5 A						
V _R	100 V						
V _F at I _F	See Electrical table						
I _{RM}	4.9 mA at 125 °C						
T _J max.	150 °C						
Diode variation	Common cathode						
E _{AS}	5 mJ						

FEATURES

- Popular D-PAK outline
- Center tap configuration
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-6CWQ10FNPbF surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	7	А						
V _{RRM}		100	V						
I _{FSM}	$t_p = 5 \ \mu s \ sine$	440	А						
V _F	3 A _{pk} , T _J = 125 °C (per leg)	0.63	V						
TJ	Range	-40 to +150	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-6CWQ10FNPbF	UNITS						
Maximum DC reverse voltage	V _R	100	N/						
Maximum working peak reverse voltage	V _{RWM}	100	v						

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBO	- TEST COND	TEST CONDITIONS						
Maximum average forward current	per leg			3.5					
	device I _{F(AV)}	50% duty cycle at $T_{\rm C} = 155$ °C,	50 % duty cycle at T_C = 135 °C, rectangular waveform						
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	440	A				
non-repetitive surge current per leo See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	70					
Non-repetitive avalanche energy pe	er leg E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 10 mH		5.0	mJ				
Repetitive avalanche current per le	g l _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.5	А				

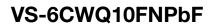
Revision: 14-Jan-11

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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS					
		3 A	T.I = 25 °C	0.81					
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	6 A	1j=23 0	0.96	v				
See fig. 1	VFM ()	3 A	T 105 %C	0.63					
		6 A	T _J = 125 °C	0.74					
Maximum reverse	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B} = \text{Rated } V_{\rm B}$	1	mA				
leakage current per leg See fig. 2		T _J = 125 °C	V _R = nated V _R	4.9	ША				
Threshold voltage	V _{F(TO)}	T T maximum		0.48	V				
Forward slope resistance	r _t	$I_{J} = I_{J} maximum$	$T_J = T_J$ maximum		mΩ				
Typical junction capacitance per leg	CT	$V_R = 5 V_{DC}$, (test signal ran	92	pF					
Typical series inductance per leg	L _S	Measured lead to lead 5 m	5.0	nH					
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs					

Note

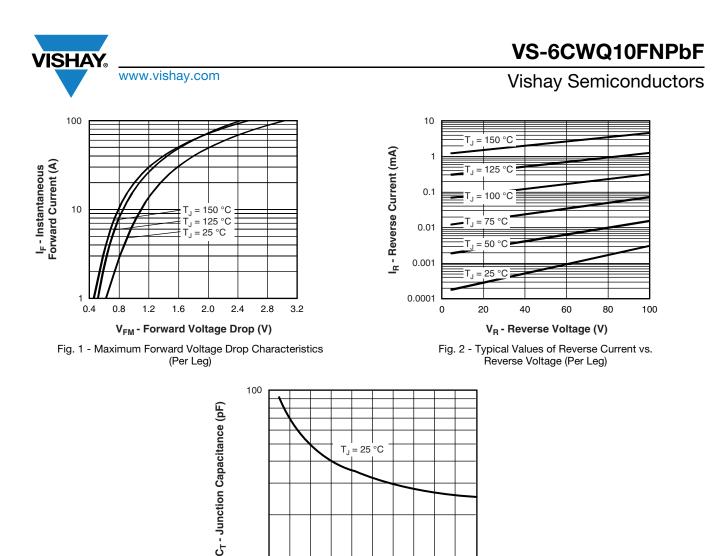
 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

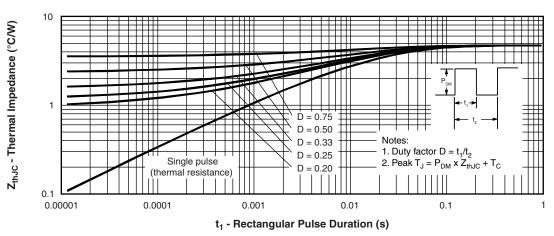
THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T _J ⁽¹⁾ , T _{Stg}		-40 to +150	°C			
Maximum thermal resistance,	per leg	P	DC operation	4.70	°C/W			
junction to case	per device	R _{thJC}	See fig. 4	2.35	0/ W			
Approximate weight				0.3	g			
				0.01	oz.			
Marking device			Case style D-PAK (similar to TO-252AA)	6CWQ10FN				

Note

(1)

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$





10

0

20

40

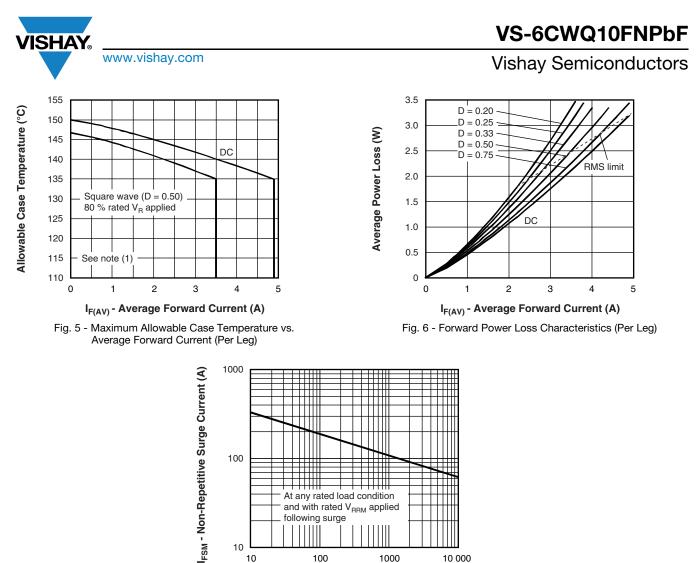
60

V_R - Reverse Voltage (V) Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

80

100

Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)



10 100 1000 10 000

t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $\begin{array}{l} \mathsf{Pd} = \mathsf{forward power loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} x \, \mathsf{V}_{\mathsf{FM}} \, \mathsf{at} \, (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \, (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse power loss} = \mathsf{V}_{\mathsf{R1}} \, x \, \mathsf{I}_{\mathsf{R}} \, (\mathsf{1} - \mathsf{D}); \, \mathsf{I}_{\mathsf{R}} \, \mathsf{at} \, \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \, \% \, \mathsf{rated} \, \mathsf{V}_{\mathsf{R}} \end{array}$

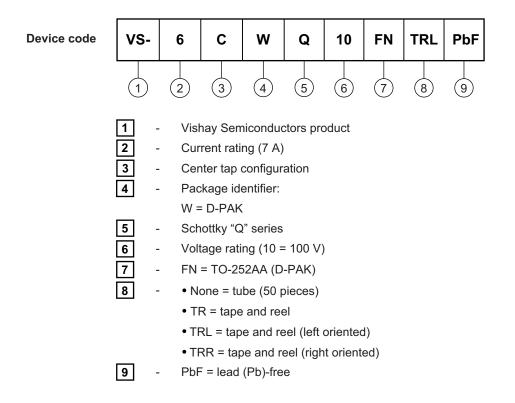
VS-6CWQ10FNPbF

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ORDERING INFORMATION TABLE

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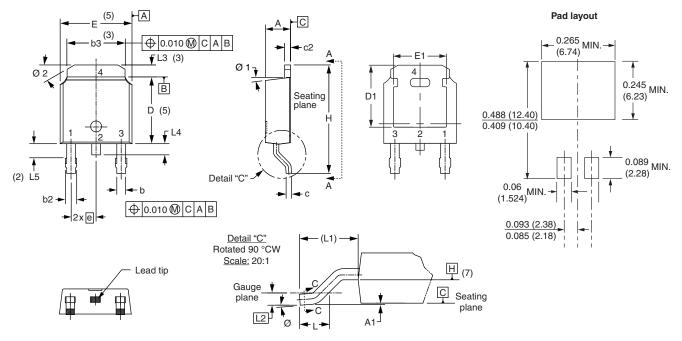
LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95016						
Part marking information	www.vishay.com/doc?95059						
Packaging information	www.vishay.com/doc?95033						



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D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	MILLIMETERS		INCHES			SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
с	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

⁽⁴⁾ Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁶⁾ Dimension b1 and c1 applied to base metal only

⁽⁷⁾ Datum A and B to be determined at datum plane H

⁽⁸⁾ Outline conforms to JEDEC outline TO-252AA

Document Number: 95016



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